CS-99-063B

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April 1, 2002

Commissioner of Patents and Trademarks

Washington, D.C. 20231

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Subject:

Serial No. 10/077,093 02/19/02

Subhash Gupta, Pradeep Yelehanka, Vijay Chhagan

METHOD TO FORM SELF-ALIGNED, L-SHAPED SIDEWALL SPACERS

Grp. Art Unit: 2812

INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation
In An Application.

The following Patents and/or Publications are submitted to comply with the duty of disclosure under CFR 1.97-1.99 and 37 CFR 1.56. Copies of each document is included herewith.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner of Patents and Trademarks, Washington, D.C. 20231, on April 10, 2002.

Stephen B. Ackerman, Reg.# 37761

Signature/Date

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- U.S. Patent 5,891,788 to Fazan et al., "Locus Isolation Technique using High Pressure Oxidation (HIPOX) and Protective Spacers", teaches a process to form local oxidation of silicon (LOCOS) isolations using polysilicon spacers around a masking material.
- U.S. Patent 5,661,049 to Lur et al., "Stress Relaxation in Dielectric before Metallization", teaches a process to form sidewalls for transistors.
- U.S. Patent 5,013,675 to Shen et al., "Method of Forming and Removing Polysilicon Lightly Doped Drain Spacers", discloses a process to form polysilicon sidewall spacers and to remove them using an etchant.
- U.S. Patent 5,899,722 to Huang, "Method of Forming Dual Spacer for Self Aligned Contact Integration", teaches a process to form sidewall spacers of silicon nitride by anisotropically etching a silicon nitride layer.
- U.S. Patent 5,498,555 to Lin, "Method of Making LDD with Polysilicon and Dielectric Spacers", discloses processes to form sidewall spacers of: oxide-polysilicon, oxide-polysiliconoxide, oxide-nitride, and oxide-nitride-oxide.

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